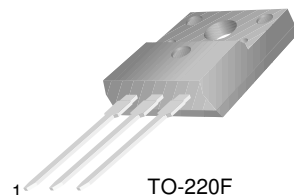


# KSD2012

## Low Frequency Power Amplifier

- Complement to KSB1366



TO-220F  
1.Base 2.Collector 3.Emitter

## NPN Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	60	V
$V_{CEO}$	Collector-Emitter Voltage	60	V
$V_{EBO}$	Emitter-Base Voltage	7	V
$I_C$	Collector Current	3	A
$I_B$	Base Current	0.3	A
$P_C$	Collector Power Dissipation ( $T_C=25^\circ\text{C}$ )	25	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	- 55 ~ 150	$^\circ\text{C}$

### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 50\text{mA}, I_B = 0$	60			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = 60\text{V}, I_E = 0$			100	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = 7\text{V}, I_C = 0$			10	$\mu\text{A}$
$h_{FE1}$	DC Current Gain	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$	100		320	
$h_{FE2}$		$V_{CE} = 5\text{V}, I_C = 3\text{A}$	20			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 2\text{A}, I_B = 0.2\text{A}$		0.4	1	V
$V_{BE(on)}$	Base-Emitter ON Voltage	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$		0.7	1	V
$f_T$	Current Gain Bandwidth Product	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$		3		MHz

### $h_{FE}$ Classification

Classification	Y	G
$h_{FE1}$	100 ~ 200	150 ~ 320

# Typical Characteristics

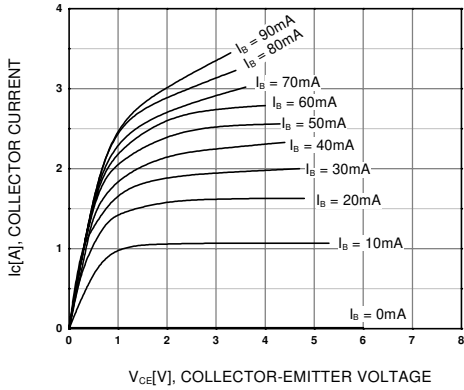


Figure 1. Static Characteristic

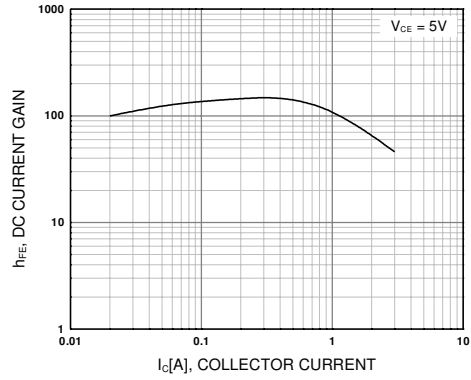


Figure 2. DC current Gain

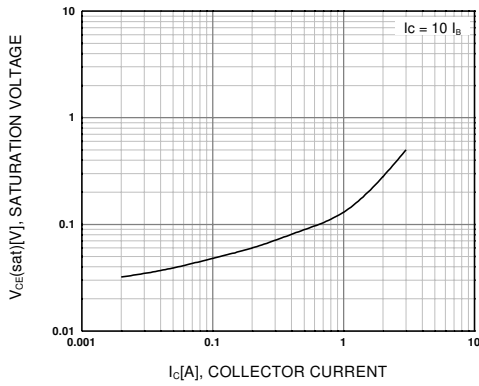


Figure 3. Collector-Emitter Saturation Voltage

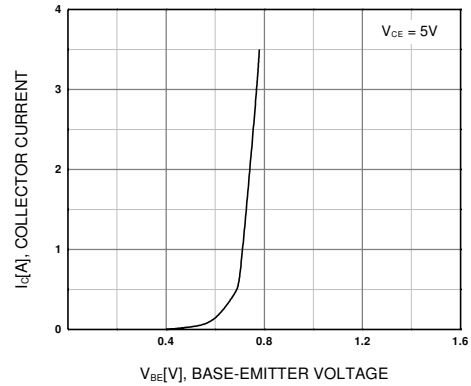


Figure 4. Base-Emitter On Voltage

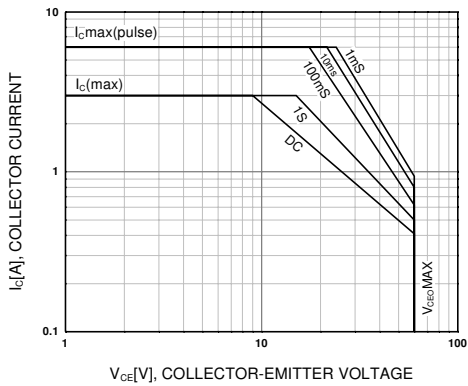


Figure 5. Safe Operating Area

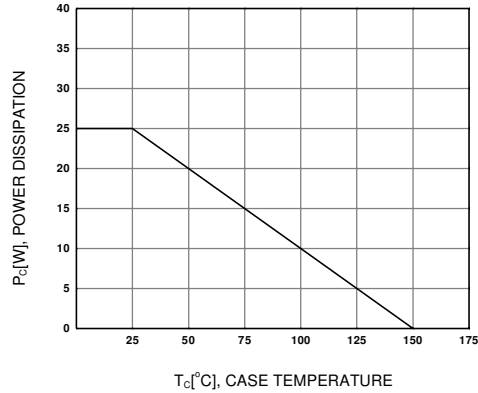
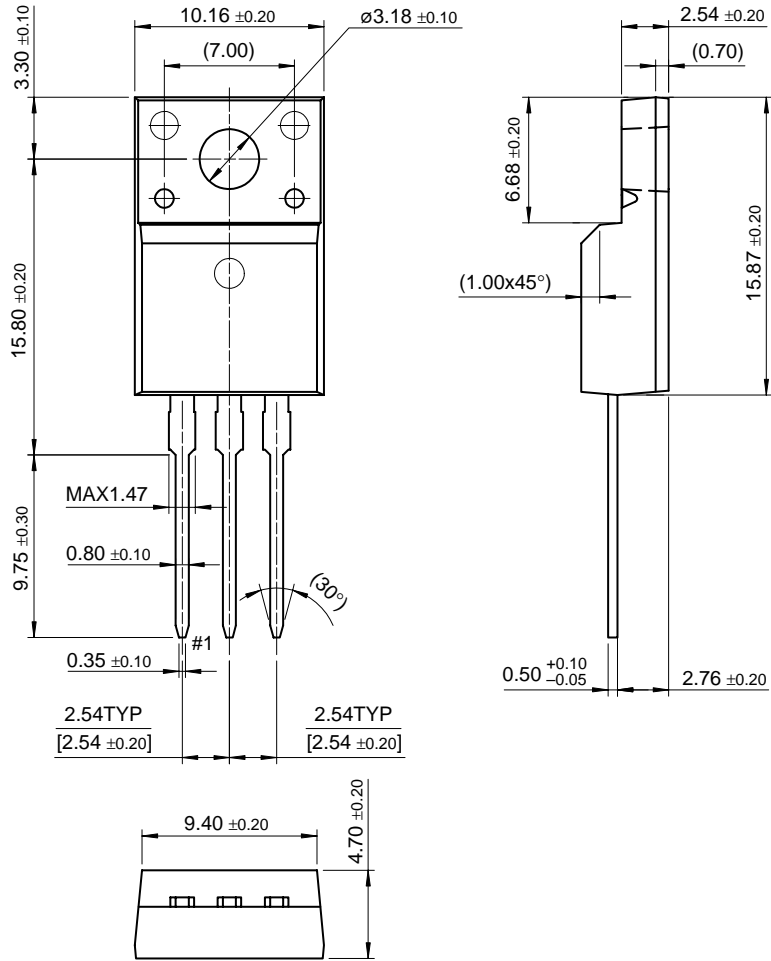


Figure 6. Power Derating

# Package Dimensions

KSD2012

## TO-220F



Dimensions in Millimeters

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GTO™	SuperSOT™-6	

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KSD2012YYDTU	Full Production		\$0.275	<a href="#">TO-220F</a>	3	RAIL	Line 1: \$Y (Fairchild logo) Line 2: D2012-Y Line 3: &3
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